



# International Journal of Scientific Research in Science and Technology

Print ISSN : 2395-6011 | Online ISSN : 2395-602X

[ UGC Journal No : 64011 ]

Peer Reviewed and Refereed International Scientific Research Journal

Scientific Journal Impact Factor : 8.62

## Certificate of Publication

Ref : IJSRST/Certificate/Volume 3/Issue 7/1587

31-Oct-2017

This is to certify that **A. K. Ghorai** has published a research paper entitled '**On Hot Electron Transport in Si(100) 2DEG at Low Lattice Temperature**' in the International Journal of Scientific Research in Science and Technology (IJSRST), Volume 3, Issue 7, September-October-2017 .

This Paper can be downloaded from the following IJSRST website link

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